

# Title AlGaAs, double-heterojunction, visible laser diodes

## RLD-78PP-G1 / RLD-78NP-G1

RLD-78PP-G1 and RLD-78NP-G1 are the semiconductor laser developed for the laser beam printer application. We have achieved the very small variations of the optical characteristics and low droop by ROHM original Epitaxial growth technology using Molecular Beam Epitaxy. In addition, they have the appropriate characteristics for sensor application as well.

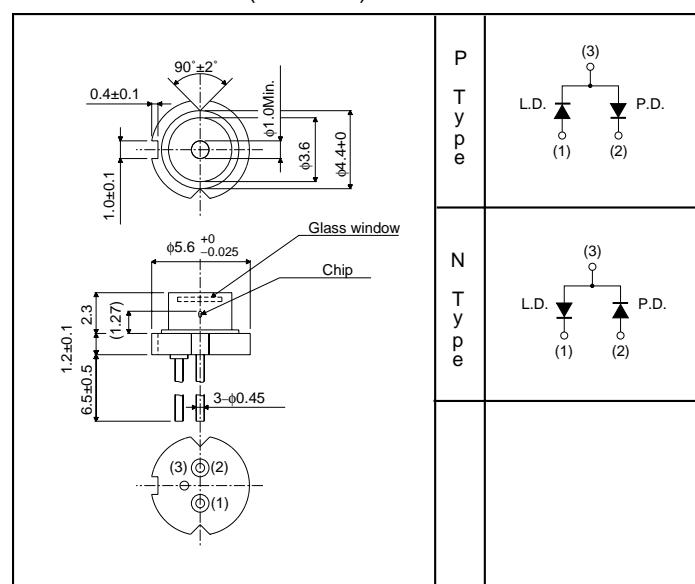
### ●Applications

Laser beam printers  
Sensors

### ●Features

- 1) Minimum variation of radiation beam angle.
- 2) Low droop.
- 3) High stability wave length.
- 4) Can be driven by single power supply.

### ●External dimensions (Units : mm)



### ●Absolute maximum ratings ( $T_c=25^\circ\text{C}$ )

Parameter		Symbol	Limits	Unit
Output		$P_o$	5	mW
Reverse voltage	Laser	$V_R$	2	V
	PIN photodiode	$V_{R(PIN)}$	30	V
Operating temperature		$T_{opr}$	-10~+60	°C
Storage temperature		$T_{stg}$	-40~+85	°C

## Laser Diodes

● Electrical and optical characteristics ( $T_a=25^\circ C$ )

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Threshold current	$I_{th}$	10	25	45	mA	-
Operating current	$I_{op}$	15	45	65	mA	$P_o=3mW$
Operating voltage	$V_{op}$	-	1.9	2.3	V	$P_o=3mW$
Differential efficiency	$\eta$	0.1	0.2	0.3	mW/mA	$\frac{2mW}{I(3mW)-I(1mW)}$
Monitor current	$I_m$	0.3	0.55	0.9	mA	$P_o=3mW$
Parallel divergence angle	$\theta_{//}^*$	8	11	15	deg	$P_o=3mW$
Perpendicular divergence angle	$\theta_{\perp}^*$	25	30	38	deg	
Parallel deviation angle	$\Delta\phi_{//}$	-	-	$\pm 2$	deg	
Perpendicular deviation angle	$\Delta\phi_{\perp}$	-	-	$\pm 3$	deg	
Emission point accuracy	$\frac{\Delta X}{\Delta Y}$ $\frac{\Delta Y}{\Delta Z}$	-	-	$\pm 80$	$\mu m$	-
Peak emission wavelength	$\lambda$	770	785	795	nm	$P_o=3mW$
Droop	$\Delta P$	-	5	10	%	$P_o=3mW$

\* $\theta_{//}$  and  $\theta_{\perp}$  are defined as the angle within which the intensity is 50% of the peak value.

## ● Electrical and optical curves

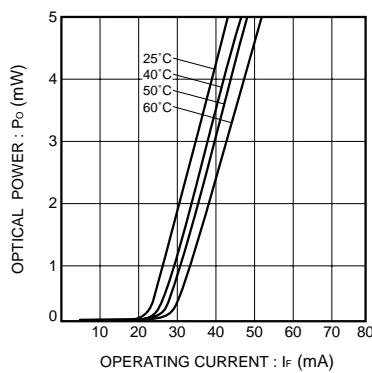


Fig. 1 Optical output vs. operating current

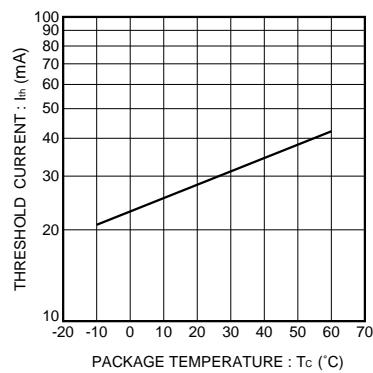


Fig. 2 Dependence of threshold current on temperature

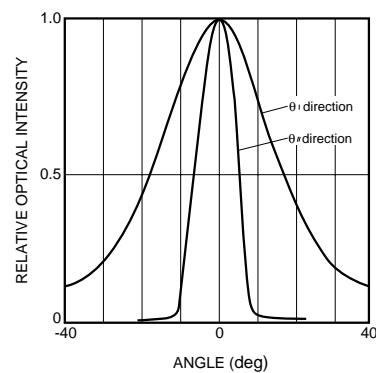


Fig. 3 Far field pattern

## Laser Diodes

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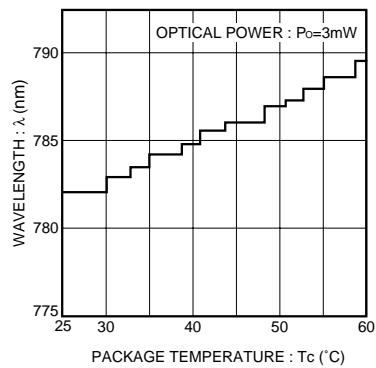


Fig. 4 Dependence of wavelength on temperature

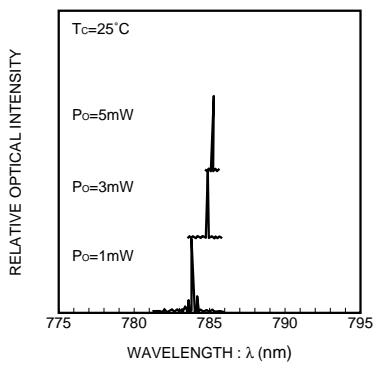


Fig. 5 Dependence of emission spectrum on optical output

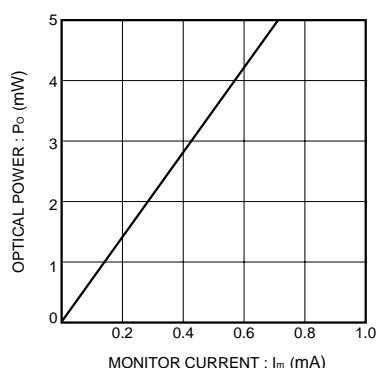


Fig. 6 Monitor current vs. optical output

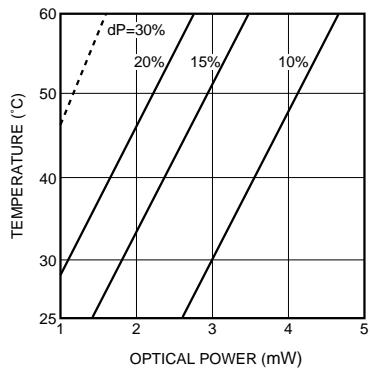


Fig. 7 Temperature vs. output guidelines for various droop percentages

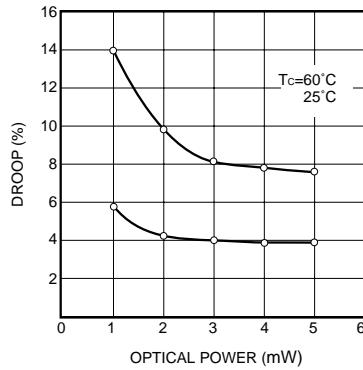


Fig. 8 Dependence of droop on output